

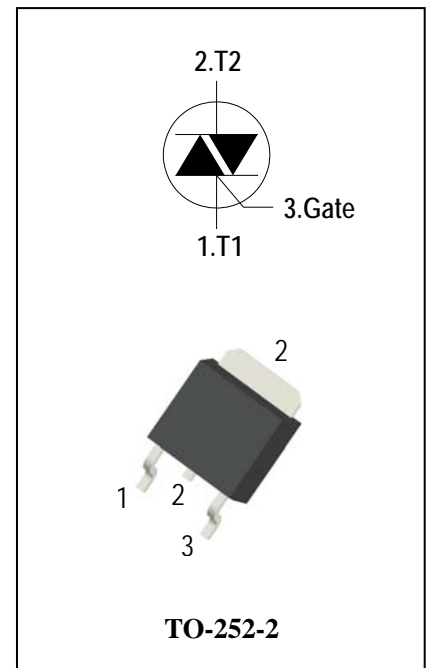
## 3 Quadrants High temperature Triacs

### General Description

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The ADS4CH triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, Rectifier-fed DC inductive loads e.g. DC motors and solenoids , motor speed controllers. The heatsink can be reduced, compared to traditional triacs, according to the high performance at given junction temperatures.

### Features

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (  $I_{T(RMS)}= 4A$  )
- ◆ High Commutation  $dv/dt$
- ◆ High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



### Absolute Maximum Ratings

| Symbol                 | Items   | Conditions  | Ratings                              | Unit       |
|------------------------|---|---|--------------------------------------|------------|
| $V_{DRM}$<br>$V_{RRM}$ | Repetitive Peak Off-State Voltage                             | $T_j = 25^\circ C$  | ADS4CH60E<br>600<br>ADS4CH80E<br>800 | V<br>V     |
| $I_{T(RMS)}$           | R.M.S On-State Current  | $T_C = 130^\circ C$   | 4                                    | A          |
| $I_{TSM}$              | Surge On-State Current  | $t_p=20ms(50Hz)/t_p=16.7ms(60Hz)$   | 30/32                                | A          |
| $I^2t$                 | $I^2t$ for fusing   | $t_p=10ms$  | 3.7                                  | $A^2s$     |
| $di/dt$                | Critical rate of rise of on-state current                     | $F = 120 Hz$ $T_j = 150^\circ C$<br>$I_G = 2 \times I_{GT}$ , $t_r \leq 100 ns$ | 50                                   | $A/\mu s$  |
| $I_{GM}$               | Peak Gate Current   | $t_p = 20 \mu s$ $T_j = 150^\circ C$  | 2                                    | A          |
| $P_{G(AV)}$            | Average Gate Power Dissipation( $T_j=150^\circ C$ )           |   | 0.5                                  | W          |
| $P_{GM}$               | Peak Gate Power Dissipation( $t_p=20\mu s, T_j=150^\circ C$ ) |   | 5                                    | W          |
| $T_j$                  | Operating Junction Temperature                                |   | - 40 ~ 150                           | $^\circ C$ |
| $T_{STG}$              | Storage Temperature   |   | - 40 ~ 150                           | $^\circ C$ |



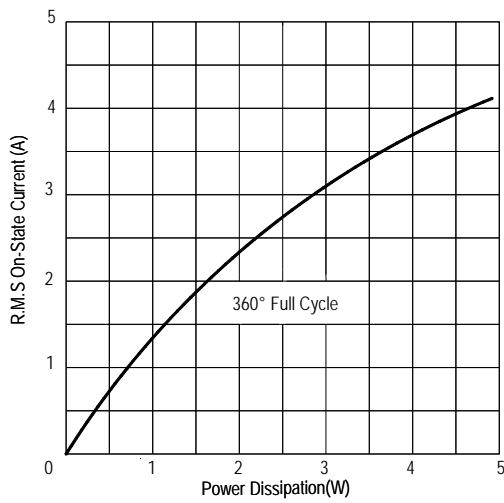
## Electrical Characteristics (T<sub>j</sub> = 25°C unless otherwise specified )

| Symbol                               | Items   |                          | Conditions  |      | ADS4CH60E/80E |       |      | Unit |
|--------------------------------------|---|--------------------------|---|------|---------------|-------|------|------|
|                                      |   |                          |   |      | S             | Blank | B    |      |
| I <sub>DRM</sub><br>I <sub>RRM</sub> | Peak Forward Reverse Blocking Current                               |                          | V <sub>DRM</sub> = V <sub>RRM</sub> , T <sub>j</sub> = 25°C                         | Max. | 5             |       |      | uA   |
|                                      |   |                          | V <sub>DRM</sub> = V <sub>RRM</sub> , T <sub>j</sub> = 150°C                        |      | 1.75          |       |      | mA   |
| V <sub>TM</sub>                      | Peak On-State Voltage   |                          | I <sub>TM</sub> = 5.5A, t <sub>p</sub> = 380 μs                                     | Max. | 1.5           |       |      | V    |
| V <sub>GD</sub>                      | Q1-Q2-Q3  | Non-Trigger Gate Voltage | V <sub>D</sub> = V <sub>DRM</sub> R <sub>L</sub> = 3.3 kΩ<br>T <sub>j</sub> = 150°C | Min. | 0.2           |       |      | V    |
| V <sub>GT</sub>                      | Q1-Q2-Q3  | Gate Trigger Voltage     | V <sub>D</sub> = 12V , R <sub>L</sub> = 33Ω   | Max. | 1.5           |       |      | V    |
| I <sub>GT</sub>                      | Q1-Q2-Q3  | Gate Trigger Current     |   | Max. | 10            | 35    | 50   | mA   |
| I <sub>H</sub>                       | Q1-Q2-Q3  | Holding Current          | I <sub>T</sub> = 0.1A   | Max. | 20            | 45    | 60   | mA   |
| I <sub>L</sub>                       | Q1-Q3   | Latching Current         | I <sub>G</sub> = 1.2 I <sub>GT</sub>  | Max. | 20            | 50    | 70   | mA   |
|                                      | Q2  |                          |   |      | 35            | 70    | 100  |      |
| dV/dt                                | Critical Rate of Rise of Off-State Voltage                          |                          | V <sub>D</sub> = 2/3V <sub>DRM</sub> gate open<br>T <sub>j</sub> = 150°C            | Min. | 200           | 1000  | 1500 | V/μs |
| (dV/dt) <sub>c</sub>                 | Critical Rate of Change of Commutating Voltage                      |                          | V <sub>D</sub> =400V T <sub>j</sub> = 150°C<br>(dI/dt) <sub>c</sub> =-1.7A/ms       | Min. | 1             | 15    | 20   | V/μs |
| R <sub>th(j-c)</sub>                 | Junction to case (AC)   |                          |   | Max. | 3.0           |       |      | °C/W |
| R <sub>th(j-a)</sub>                 | Junction to ambient(Copper surface under tab:S=0.5cm <sup>2</sup> ) |                          |   | Max. | 70            |       |      | °C/W |

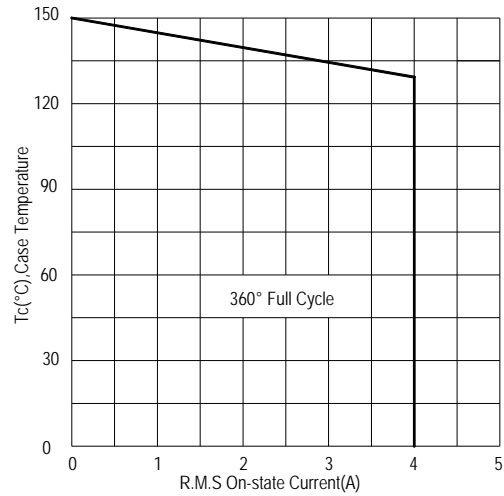
**FIG.1:Triac quadrant are defined and the gate trigger test circuit**



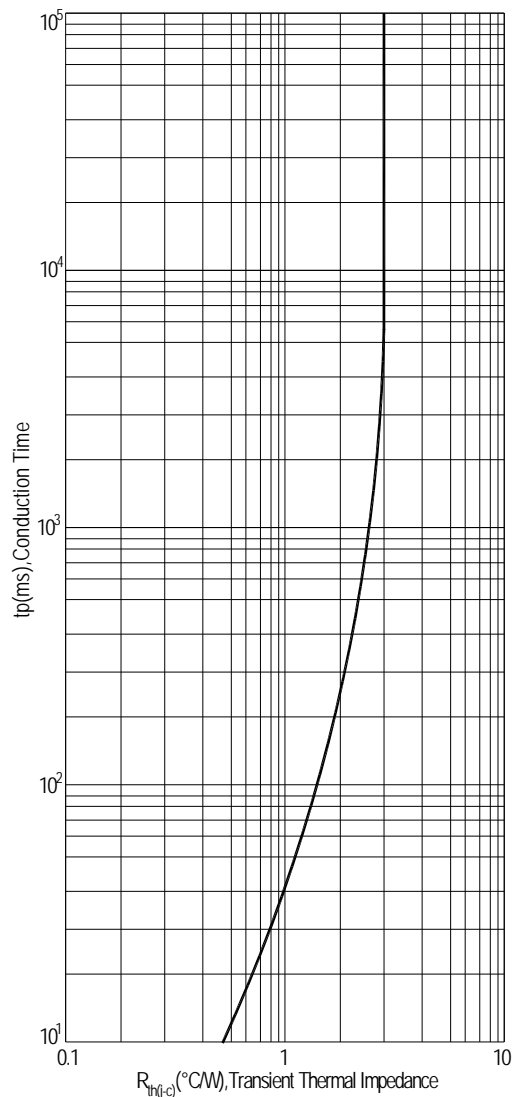
**FIG.2: Maximum on-state power dissipation**



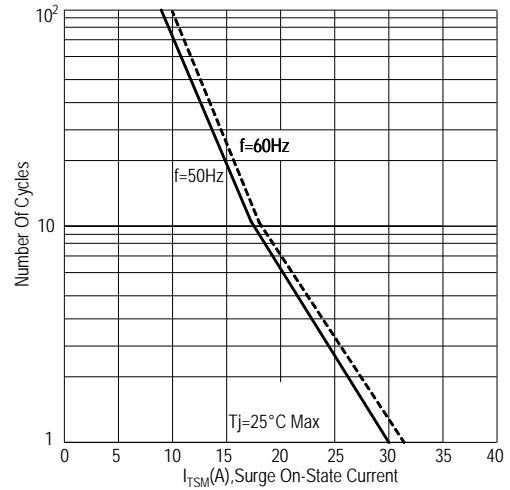
**FIG.3: Typical RMS on-state current VS Allowable case Temperature**



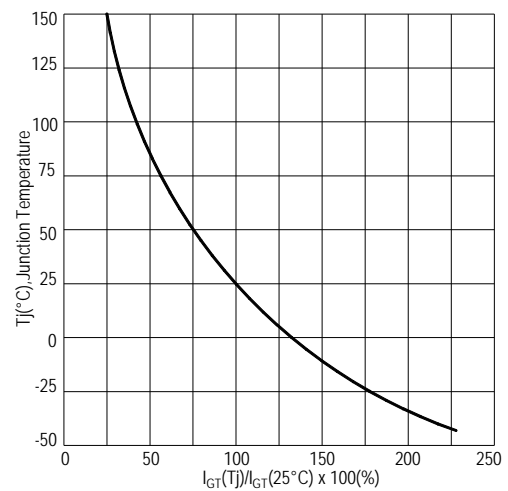
**FIG.4: Maximum transient thermal impedance**



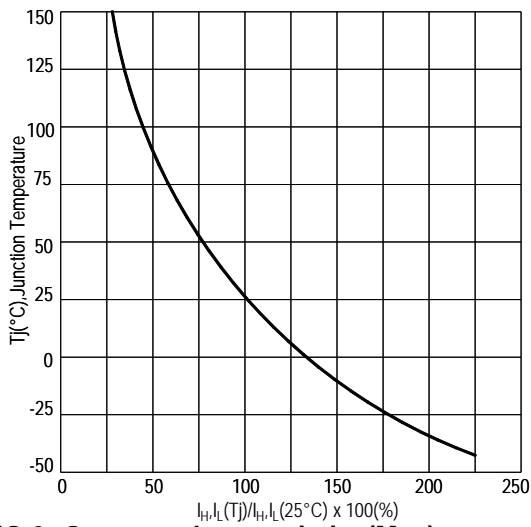
**FIG.5: Rated surge on-state current (Non-Repetitive)**



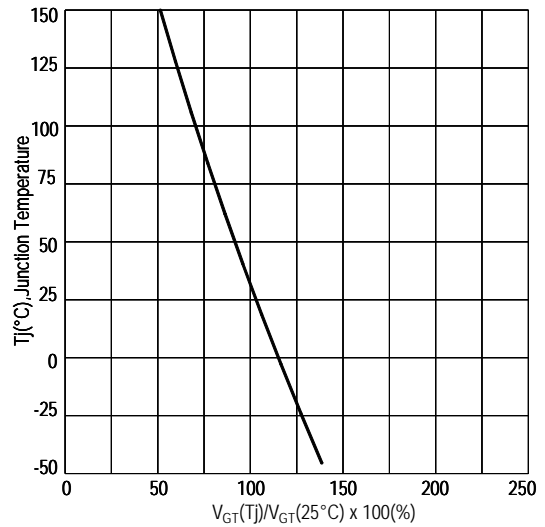
**FIG.6: Gate trigger current VS Junction temperature**



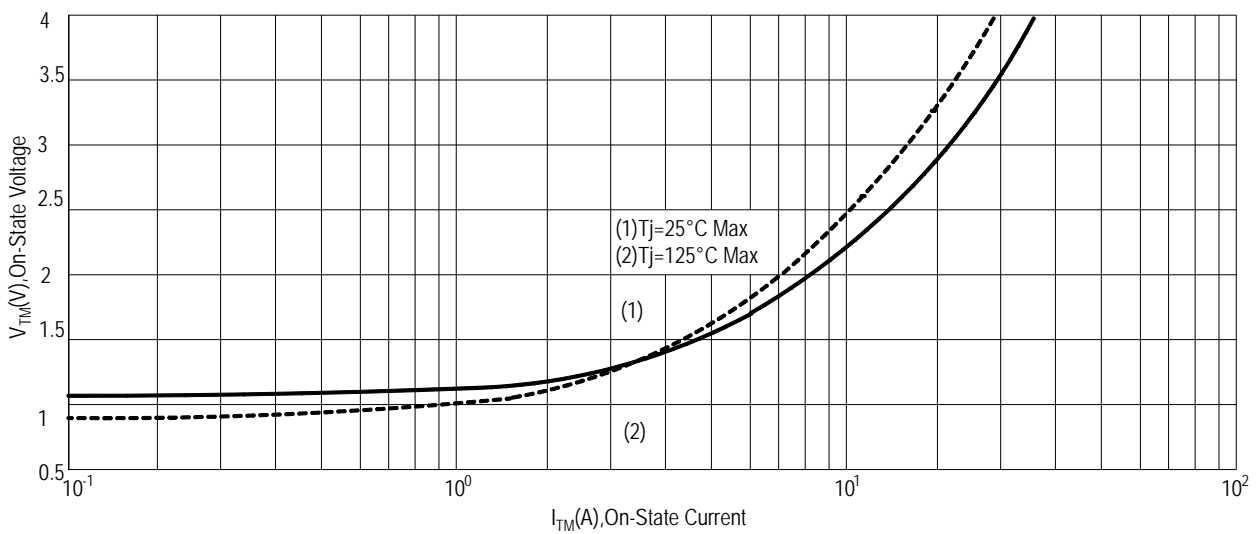
**FIG.7: Holding current and Latching current VS Junction temperature**



**FIG.8: Gate trigger voltage VS Junction temperature**

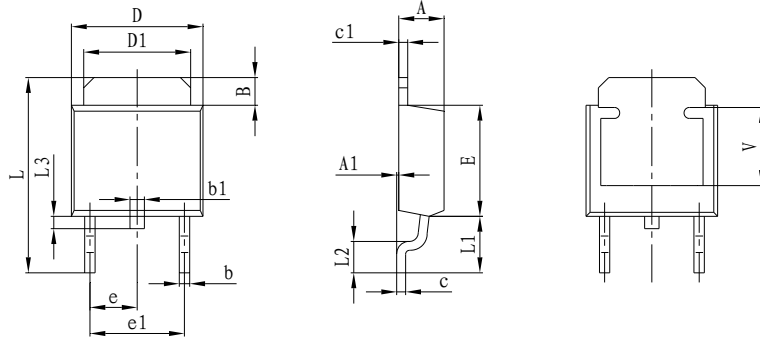


**FIG.9: On-state characteristics(Max)**



## PACKAGE MECHANICAL DATA

### TO-252-2 Package Dimension



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min.                      | Max.  | Min.                 | Max.  |
| A      | 2.200                     | 2.400 | 0.087                | 0.094 |
| A1     | 0.000                     | 0.127 | 0.000                | 0.005 |
| B      | 1.350                     | 1.650 | 0.053                | 0.065 |
| b      | 0.500                     | 0.700 | 0.020                | 0.028 |
| b1     | 0.700                     | 0.900 | 0.028                | 0.035 |
| c      | 0.450                     | 0.620 | 0.017                | 0.024 |
| c1     | 0.450                     | 0.620 | 0.017                | 0.024 |
| D      | 6.350                     | 6.650 | 0.250                | 0.262 |
| D1     | 5.100                     | 5.400 | 0.200                | 0.213 |
| E      | 5.900                     | 6.200 | 0.232                | 0.244 |
| e      | 2.300 TYP.                |       | 0.091 TYP.           |       |
| e1     | 4.500                     | 4.700 | 0.177                | 0.185 |
| L      | 9.500                     | 10.60 | 0.374                | 0.396 |
| L1     | 2.550                     | 2.900 | 0.100                | 0.114 |
| L2     | 1.400                     | 1.780 | 0.055                | 0.070 |
| L3     | 0.600                     | 0.900 | 0.024                | 0.035 |
| V      | 4.100 REF.                |       | 0.161 REF.           |       |

### Making Diagram

**ADV**: Logo  
**ADS4CH60EB**: Part number  
**X**: Internal control code  
**H**: Halogen Free

A D S 4 C H 6 0 E S ( B )

|                           |   |   |   |   |    |   |   |
|---------------------------|---|---|---|---|----|---|---|
| ADVANCED                  | S | 4 | C | H | 60 | E | S(B)  |
| Internal control code     |   |   |   |   |    |   | Sensitivity and type:<br>S=10mA<br>Blank=35mA<br>B=50mA |
| Current: 4=4A             |   |   |   |   |    |   |   |
| Quadrant: C=3Q            |   |   |   |   |    |   |   |
| High temperature: H=150°C |   |   |   |   |    |   |   |
|                           |   |   |   |   |    |   | Package explain: E=TO-252-2<br>Voltage: 60=600V 80=800V |

### Ordering information

| Part number | Package  | Marking    | Packing       | Quantity |
|-------------|----------|------------|---------------|----------|
| ADS4CH60E#  | TO-252-2 | ADS4CH60E# | Tube          | 80pcs    |
|             |          |            | Embossed tape | 2500pcs  |
| ADS4CH80E#  | TO-252-2 | ADS4CH80E# | Tube          | 80pcs    |
|             |          |            | Embossed tape | 2500pcs  |

Note: # = Gate Trigger Current Sensitivity and type

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